_____查询2SC4365供应商

Ordering number:EN3007

NPN Epitaxial Planar Silicon Transistor

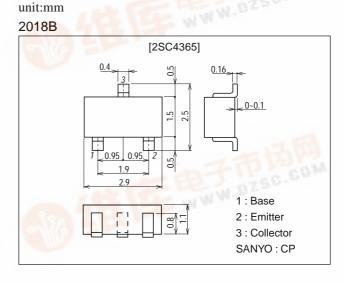
2SC4365

VHF, UHF/MIX. OSC. Low-Voltage High-Frequency Amplifier Applications

Features

- · Low-voltage operation
 - : $f_T=3.0GHz typ (V_{CE}=3V)$
 - : MAG=12dB typ (V_{CE} =3V, I_C =10mA)
 - : NF=1.5dB typ (V_{CE} =3V, I_C =5mA)

Package Dimensions



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		25	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	V _{EBO}	14	3	V
Collector Current	IC		50	mA
Collector Dissipation	PC	1 h h h h h h h h h h h h h h h h h h h	250	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Falalleter	Symbol	Conditions		typ	max	
Collector Cutoff Current	Ісво	V _{CB} =15V, I _E =0			1.0	μA
Emitter Cutoff Current	IEBO	V _{EB} =1V, I _C =0			1.0	μA
DC Current Gain	hFE	V _{CE} =3V, I _C =10mA	40*		200*	
Gain-Bandwidth Product	fT	V _{CE} =3V, I _C =10mA		3.0	173	GHz
Output Capacitance	Cob	V _{CB} =3V, f=1MHz	101-	0.9	1.5	pF
Reverse Transfer Capacitance	C _{re}	V _{CB} =3V, f=1MHz		0.85	a second	pF

* : The 2SC4365 is classified by 10mA h_{FE} as follows : 40 2 80 60 3 120 100 4 200

(Note) Marking : PT

h_{FE} rank : 2, 3, 4

Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.

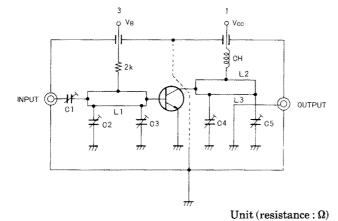
SANYO assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges,or other parameters) listed in products specifications of any and all SANYO products described or contained
F herein.

SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

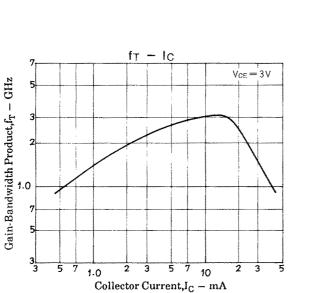
2SC4365

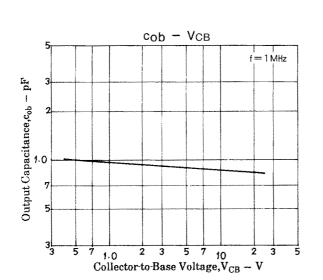
Parameter	Symbol	Conditions		Ratings		
Falanielei	Symbol Conditions .		min	typ	max	Unit
Forward Transfer Gain	S21e ²	V _{CE} =3V, I _C =10mA, f=0.9GHz		7		dB
Maximum Available Power Gain	MAG	V _{CE} =3V, I _C =10mA, f=0.9GHz		12		dB
Noise Figure	NF	$V_{CE}=3V$, I _C =5mA, f=0.9GHz		1.5	3.0	dB

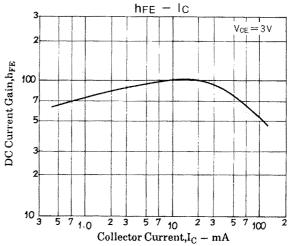
NF Test Circuit

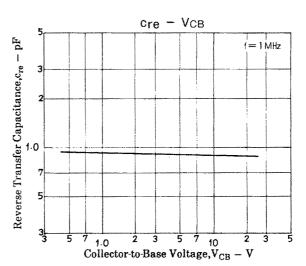


	900MHz
C1	~5pF
C2	~10pF
C3	~10pF
C4	~10pF
C5	~10pF
L1	W ≈ 1.5mm, I ≈ 25mm Strip line
L2	W ≈ 4mm, I ≈ 25mm Strip line
L3	0.5¢, I ≈ 40mm
СН	2t+bead core

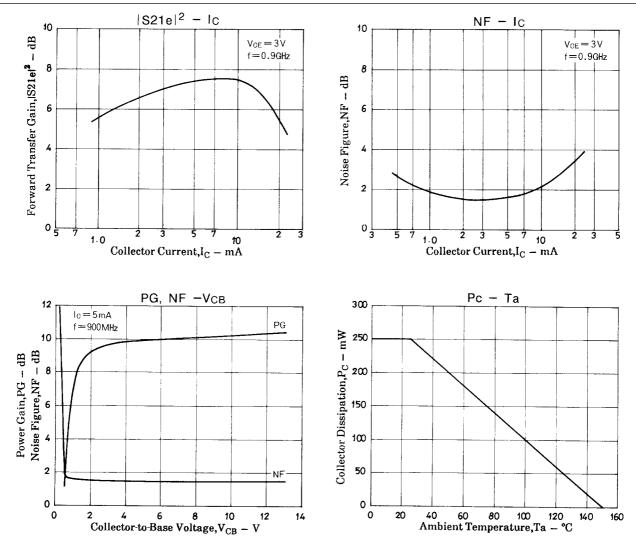






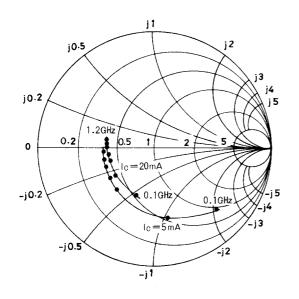


2SC4365

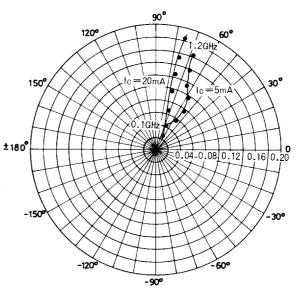


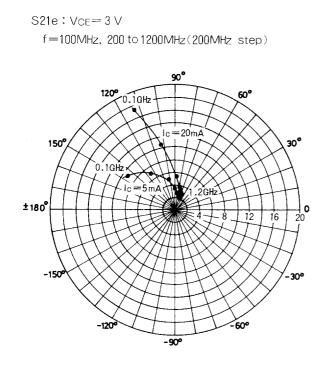
S parameter

S11e: V_{CE}= 3 V f=100MHz, 200 to1200MHz(200MHz step)

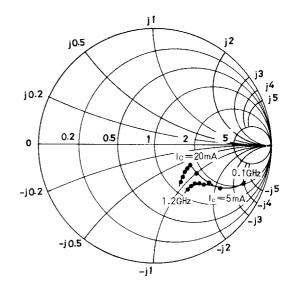


S12e: V_{CE}= 3 V f=100MHz, 200 to 1200MHz(200MHz step)









S parameter (Common emitter)

 V_{CE} =3V, I_C =5mA, Z_O =50 Ω

Freq (MHz)	S ₁₁	∠s ₁₁	S ₂₁	∠s ₂₁	S ₁₂	∠s ₁₂	S ₂₂	∠ S ₂₂
100	0.738	-45.7	9.352	143.7	0.040	65.0	0.827	-22.5
200	0.606	-80.3	7.183	123.9	0.059	54.4	0.664	-31.3
400	0.485	-129.6	4.814	99.4	0.079	53.5	0.506	-35.3
600	0.449	-149.5	3.426	87.4	0.097	58.1	0.463	-38.1
800	0.437	-161.2	2.626	78.8	0.115	63.5	0.444	-41.4
900	0.437	-165.9	2.392	75.6	0.127	65.2	0.446	-43.3
1000	0.444	-170.2	2.180	72.3	0.138	67.3	0.444	-45.4
1200	0.448	-175.7	1.891	66.8	0.163	69.0	0.451	-50.4

$V_{CE}{=}3V\!,\,I_{C}{=}20mA,\,Z_{O}{=}50\Omega$

Freq (MHz)	S ₁₁	∠ s ₁₁	S ₂₁	∠ s ₂₁	S ₁₂	∠s ₁₂	S ₂₂	∠ S ₂₂
100	0.446	-112.7	17.471	118.5	0.026	61.5	0.581	-32.6
200	0.421	-143.4	10.341	102.4	0.040	65.0	0.437	-32.2
400	0.414	-164.8	5.545	88.2	0.067	71.7	0.370	-30.5
600	0.412	-173.5	3.742	79.9	0.096	74.1	0.361	-34.4
800	0.412	-178.4	2.822	73.4	0.123	75.8	0.359	-39.1
900	0.418	179.1	2.566	70.9	0.139	75.6	0.365	-41.5
1000	0.428	176.8	2.326	68.1	0.153	76.0	0.366	-44.2
1200	0.435	174.0	2.013	63.2	0.182	74.9	0.398	-50.2

- Specifications of any and all SANYO products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Electric Co., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO products(including technical data,services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of SANYO Electric Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of December, 1998. Specifications and information herein are subject to change without notice.